

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	37	((WOLFGANG) near2 (CLEMENS)).INV.	US-PGPUB; USPAT	ADJ	ON	2007/11/21 08:43
S2	2	((DIETMAR) near2 (ZIPPERER)).INV.	US-PGPUB; USPAT	ADJ	ON	2007/11/21 08:43
S3	551	361/523.ccls.	US-PGPUB; USPAT	ADJ	ON	2007/11/21 08:44
S4	27204	capacitor and insulator and semiconductor and electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/08 14:41
S6	1667	capacitor.ab. and insulator and semiconductor and electrode and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/08 14:41
S7	132	capacitor.ab. and insulator and semiconductor and electrode and organic and structured	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/08 14:42
S8	2	("3512052").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/05/08 14:51
S9	9	("3512052").URPN.	USPAT	ADJ	ON	2008/05/08 14:51
S10	89	("20020022284"   "20020025391"   "20020053320"   "20020056839"   "20020068392"   "20020130042"   "20020167003"   "20020170897"   "20020195644"   "20030059987"   "20030112576"   "20030175427"   "20040002176"   "20040013982"   "20040026689"   "20040084670"   "20040211329"   "3512052"   "3769096"   "3955098"   "4302648"   "4340657"   "4442019"   "4865197"   "4937119"	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/05/08 14:54

		"5173835"   "5206525"   "5259926"   "5321240"   "5347144"   "5364735"   "5395504"   "5480839"   "5486851"   "5502396"   "5546889"   "5569879"   "5574291"   "5578513"   "5580794"   "5625199"   "5630986"   "5652645"   "5691089"   "5705826"   "5729428"   "5854139"   "5869972"   "5883397"   "5892244"   "5967048"   "5970318"   "5973598"   "5994773"   "5997817"   "5998805"   "6036919"   "6045977"   "6072716"   "6083104"   "6087196"   "6133835"   "6150668"   "6197663"   "6207472"   "6215130"   "6221553"   "6251513"   "6284562"   "6300141"   "6321571"   "6322736"   "6329226"   "6330464"   "6335539"   "6340822"   "6344662"   "6362509"   "6384804"   "6403396"   "6429450"   "6498114"   "6517995"   "6555840"   "6593690"   "6603139"   "6621098"   "6852583").PN. OR ("7064345").URPN.				
S11	57	("5347144"   "5355235").PN. OR ("5705826").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/05/08 14:58
S12	70	capacitor.ab. and insulator layer and semiconductor layer and electrode and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/08 16:06

S13	13733	FET and capacitor same source same drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:29
S14	4685	FET and electrode and semiconductor and p near type and n near type and insulator and voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:29
S15	2215	FET and structure with electrode and semiconductor and p near type and n near type and insulator and voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:31
S16	882	FET and structure with electrode and semiconductor and p near type and n near type and insulator and voltage and capacitor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:31
S17	122	FET and structure with electrode and semiconductor and p near type and n near type and insulator and voltage and capacitor and organic with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:34
S18	1758	FET and electrode and semiconductor and p near type and n near type and insulator and voltage and first with semiconductor with layer and second with semiconductor with layer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 13:39
S19	359	FET and electrode and semiconductor and p near type and n near type and insulator and voltage and first with semiconductor with layer and second with semiconductor with layer and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:01
S20	998	FET and electrode and semiconductor and p near type and n near type and insulator and voltage and organic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:03

S21	349	FET and electrode and semiconductor and p near type and n near type and insulator and voltage and organic and source with metal and drain with metal	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:05
S23	2862	capacitor and electrode and organic same semiconductor and first with semiconductor and second with semiconductor and (insualtor or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:25
S24	1712	capacitor and electrode and organic with semiconductor and first with semiconductor and second with semiconductor and (insualtor or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:25
S25	9	("3512052").URPN.	USPAT	ADJ	ON	2008/05/14 14:26
S26	1154	capacitor and electrode and organic with semiconductor and first with semiconductor with layer and second with semiconductor with layer and (insualtor or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:29
S27	314	(capacitor.ab. or capacitor.clm. or capcitor.ti.) and electrode and organic with semiconductor and first with semiconductor with layer and second with semiconductor with layer and (insualtor or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:39
S29	29476	(field effect transistor or capacitor) and (first with semiconductor) same (second with semiconductor) and electrode and (insulator or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:50

S30	5067	(field effect transistor or capacitor) and (first with semiconductor) same (second with semiconductor) with electrode with (insulator or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:51
S31	3971	(capacitor) and (first with semiconductor) same (second with semiconductor) with electrode with (insulator or dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 14:52
S32	311	361/277.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 15:07
S33	470	361/278.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 15:07
S34	223	361/281.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/14 15:35
S36	1	("5694355").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/05/14 16:01
S37	1	("6791402").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/05/14 16:02
S38	6666	FET and capacitor same source with drain with connect\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 06:35
S39	7848	capacitor.ab. and insulator and semiconductor and electrode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 06:39
S40	6666	FET and capacitor same source with drain with connect\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 08:01
S41	1639	FET.ab. and capacitor same source with drain with connect\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 08:03
S42	4791	FET and capacitor same source near5 connect\$4 near5 drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 09:04

S43	0	FET and capacitor same source is connected to the drain	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 09:10
S45	460	capacitor and (insulator or dielectric) and (electrode or conductive plate) and (ptype or p near type) and (ntype or n near type) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:19
S46	5	("5384649"   "5583676").PN. OR ("6219170").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2008/05/15 11:27
S47	27	capacitor and (insulator or dielectric) and (electrode or conductive plate) and (ptype or p near type) and (ntype or n near type) and semiconductor not silicon	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:32
S48	0	semiconductor near3 insulator near3 semiconductor near3 (electrode or conductor or conductive plate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:33
S49	1	semiconductor with insulator with (electrode or conductor or conductive plate)	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:36
S51	44	semiconductor-insulator-semiconductor and capacitor	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:42
S52	1	("5298762").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/05/15 11:51
S53	8	semiconductor insulator semiconductor and capacitor and ohmic contact	US-PGPUB; USPAT; EPO; JPO; DERWENT	ADJ	ON	2008/05/15 11:52

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